

Schottky Barrier Rectifiers

Using the Schottky Barrier principle with a Molybdenum barrier metal. These state-of-the-art geometry features epitaxial construction with oxide passivation and metal overlay contact. Ideally suited for low voltage, high frequency rectification, or as free wheeling and polarity protection diodes.

Features

- *Low Forward Voltage.
- *Low Switching noise.
- *High Current Capacity
- *Guarantee Reverse Avalanche.
- * Guard-Ring for Stress Protection.
- *Low Power Loss & High efficiency.
- *150°C Operating Junction Temperature
- *Low Stored Charge Majority Carrier Conduction.
- $*\, \textbf{Plastic Material used Carries Underwriters Laboratory}$

Flammability Classification 94V-O

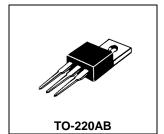
*ESD: 8KV(Min.) Human-Body Model

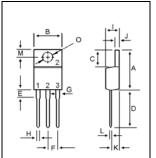
* In compliance with EU RoHs 2002/95/EC directives



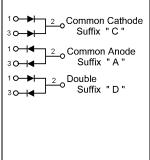
SCHOTTKY BARRIER RECTIFIERS

16 AMPERES 30~60 VOLTS





DIM	MILLIMETERS			
DIIVI	MIN	MAX		
Α	14.68	16		
В	9.78	10.42		
С	5.02	6.6		
D	13	14.62		
E	3.1	4.19		
F	2.41	2.67		
G	1.1	1.67		
Н	0.69	1.01		
- 1	4.22	4.98		
J	1.14	1.4		
K	2.2	3.3		
L	0.279	0.61		
M	2.48	3		
0	3.5	4		



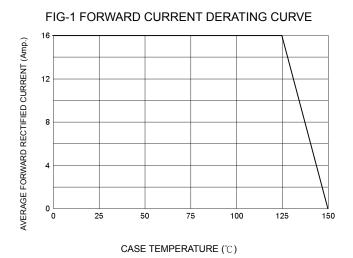
MAXIMUM RATINGS

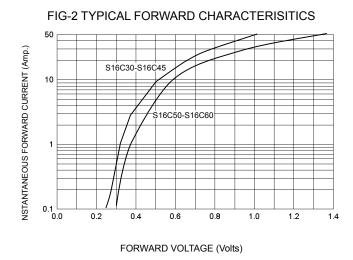
Charactariatia	Symbol	S16C						1111
Characteristic		30	35	40	45	50	60	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	30	35	40	45	50	60	٧
RMS Reverse Voltage	V _{R(RMS)}	21	25	28	32	35	42	٧
Average Rectifier Forward Current Total Device (Rated V _R), T _C =100°C	I _{F(AV)}	8.0 16				А		
Peak Repetitive Forward Current (Rate V _R , Square Wave, 20kHz)	I _{FM}	16			А			
Non-Repetitive Peak Surge Current (Surge applied at rate load conditions halfware, single phase, 60Hz)	I _{FSM}	150			А			
Operating and Storage Junction Temperature Range	T _J , T _{stg}	-65 to +150					$^{\circ}$	

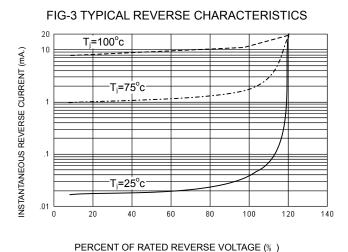
ELECTRICAL CHARACTERISTICS

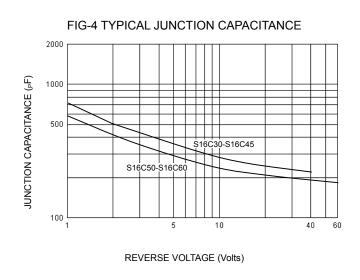
Characteristic	Symbol	S16C						l lmit
Characteristic		30	35	40	45	50	60	Unit
Maximum Instantaneous Forward Voltage ($I_F = 8 \text{ Amp } T_C = 25^{\circ}C$) ($I_F = 8 \text{ Amp } T_C = 100^{\circ}C$)	V _F	0.55 0.48						٧
Typical Thermal Resistance junction to case	R _{θ j-c}	3.8				°C/w		
Maximum Instantaneous Reverse Current (Rated DC Voltage, $T_C = 25^{\circ}C$) (Rated DC Voltage, $T_C = 125^{\circ}C$)	I _R	0.5 20						mA

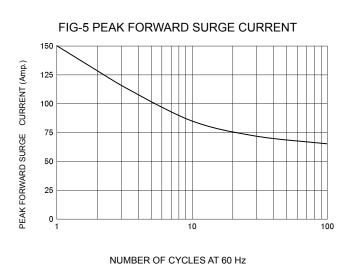
S16C30 Thru S16C60













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